Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

1.103 inches

Mounting Facility Quantity:

1

Electrode Internally-electrically Connected To Case:

Cathode

Mounting Method:

Threaded hole

Thread Size:

0.107 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

62.0 regulator voltage

Current Rating Per Characteristic:

0.25 amperes source cutoff current

Power Rating Per Characteristic:

1.5 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Thread Series Designator:

Unc

Terminal Type And Quantity:

2 insulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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